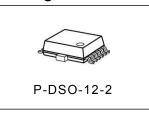


Smart High-Side Power Switch Two Channels: $2 \times 25m\Omega$ IntelliSense

Product Summary

Operating voltage	V _{bb(on)}	4,5	28	V
		(Loaddur	mp: 40 V)	
Active	channels	one		
On-state resistance	R _{ON}	25	mΩ	
Nominal load current	I _{L(nom)}	6	6 9,1	
Current limitation Low	I _{L(SCr)}		А	
High				

Package



General Description

- N channel vertical power MOSFET with charge pump, ground referenced CMOS compatible input and diagnostic feedback, monolithically integrated in Smart SIPMOS[®] technology.
- Providing embedded protective functions.
- Extern adjustable current limitation.

Application

- All types of resistive, inductive and capacitive loads
- µC compatible high-side power switch with diagnostic feedback for 12 V grounded loads
- Due to the adjustable current limitation best suitable for loads with high inrush currents, so as lamps
- Replaces electromechanical relays, fuses and discrete circuits

Basic Functions

- Very low standby current
- CMOS compatible input
- Improved electromagnetic compatibility (EMC)
- Stable behaviour at low battery voltage

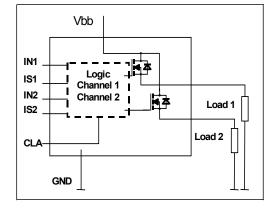
Protection Functions

- Reverse battery protection with external resistor
- Short circuit protection
- Overload protection
- Current limitation
- Thermal Shutdown
- Overvoltage protection with external resistor
- Loss of GND and loss of V_{bb} protection
- Electrostatic discharge Protection (ESD)

Diagnostic Function: IntelliSense

- Proportional load current sense (with defined fault signal during thermal shutdown and overload)
- Additional open load detection in OFF state
- Suppressed thermal toggling of fault signal

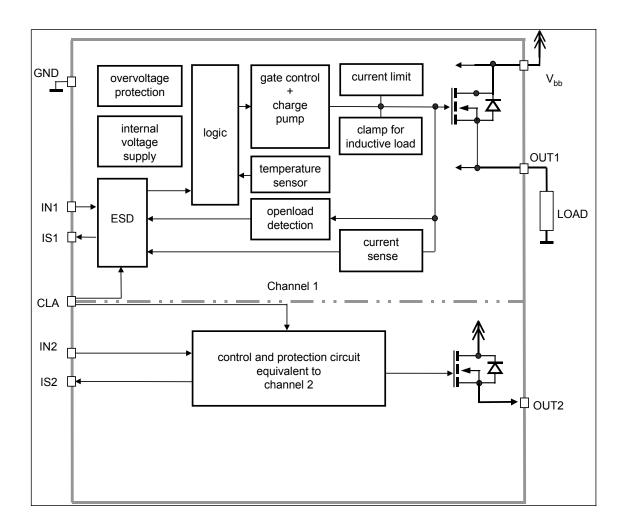
Block Diagram







Functional diagram

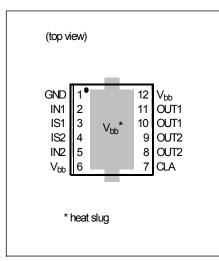




Pin definition and function

Pin	Symbol	Function
2	IN1	Input 1,2 activates channel1,2 in case of logic high signal
5	IN2	
3	IS1	Diagnostic feedback 1 & 2 of channel 1,2
		On state: advanced current sense with defined signal in case
4	IS2	of overload or short circuit
		Off state: High on failure
1	GND	Ground of chip
6,12,	V _{bb}	Positive power supply voltage. Design the wiring for the
heat		simultaneous max. short circuit currents from channel 1 to 2 and
slug		also for low thermal resistance
7	CLA	Current limit adjust, the current limit for both channels can be
		chosen as high (potential < 2V) or low (potential > 4V).
8,9	OUT2	Output 1,2 protected high-side power output of channel 1,2.
10,11	OUT1	Design the wiring for the max. short circuit current.

Pin configuration





Supply voltage (overvoltage protection see page 6) V_{bb} 281)VSupply voltage for full short circuit protection; $T_i = -40150^{\circ}$ C $V_{bb}(SC)$ 28^{21} Maximum voltage across DMOS V_{ON} 52 Load dump protection ³) $V_{LoadDump} = V_A + V_S$; $V_A = 13.5$ V $V_{Loaddump}$ In = low or high; $t_d = 400$ ms; $R_1^{(4)} = 2 \Omega$ 40 $R_L = 2.25 \Omega$ 40 $R_L = 6.8 \Omega$ 53 Load current (Short - circuit current, see page 7) I_L I_L ($I_L(lim)^5$)AOperating temperature range T_i Storage temperature range T_{stg} $-55+150$ C Dynamical temperature rise at switching dT $d0$ KPower dissipation ⁶) (DC), one channel active $T_A = 85 ^{\circ}$ C $V_{bb} = 12V$, $T_{jstart} = 150^{\circ}$ C; (see diagrams on page 12) $H_L = 6A, E_{AS} = 0.319 J, R_L = 0 \Omega$, one channel: $H_L = 12 A, E_{AS} = 0.679 J, R_L = 0 \Omega$, two parallel channels: 5.2 Electrostatic discharge voltageIN: V_{ESD} $(Human Body Model)$ IS: 2.0 according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998 OUT: 4.0 Continuous input voltage V_{IN} -1016 Voltage at current limit adjustment pin I_{CLA} ± 5.0						
Supply voltage (or or or lage protocol roce page of the page	Parameter	Symbol	Value	Unit		
Maximum voltage across DMOS V_{ON} 52Load dump protection 3) $V_{LoadDump} = V_A + V_S$; $V_A = 13,5$ V V_{ON} 52In = low or high; $t_d = 400$ ms; $R_l^{(4)} = 2 \Omega$ 40 $R_L = 2.25 \Omega$ 40 $R_L = 6.8 \Omega$ 53Load current (Short - circuit current, see page 7) I_L I_L (limin) 5)AOperating temperature range T_i -40+150°CStorage temperature range T_{stg} Operating temperature range $T_{a} = 85$ °CPower dissipation 6) (DC), one channel active $T_A = 85$ °CPower dissipation 6) (DC), one channel active $T_A = 85$ °CV_{bb} = 12V, $T_{jstart} = 150$ °C;(see diagrams on page 12) $I_L = 6 A, E_{AS} = 0.319 J, R_L = 0 \Omega$, two parallel channels: 5.2 Electrostatic discharge voltageIN: V_{ESD} $I_L = 12 A, E_{AS} = 0.679 J, R_L = 0 \Omega$, two parallel channels: 5.2 Electrostatic discharge voltageIN: V_{esD} V_{IN} -1016VVoltage at current limit adjustment pin V_{CLA} -1016Current through current limit adjustment pin I_{CLA} ± 5.0	Supply voltage (overvoltage protection see page 6)	V _{bb}	281)	V		
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Supply voltage for full short circuit protection; $T_j = -40150^{\circ}C$	V _{bb(SC)}	28 ²⁾			
In = low or high; $t_d = 400 \text{ ms}; R_1^{(4)} = 2 \Omega$ 40 $R_L = 2.25 \Omega$ 40 $R_L = 6.8 \Omega$ 53Load current (Short - circuit current, see page 7) I_L $I_{L(lim)}^{(5)}$ Operating temperature range T_1 -40+150Storage temperature range T_{stg} -55+150Dynamical temperature rise at switching dT 60KPower dissipation ⁶) (DC), one channel active $T_A = 85 \text{ °C}$ P_{tot} Power dissipation ⁶) (DC), one channel active $T_A = 85 \text{ °C}$ P_{tot} 1.4WMaximal switchable inductance, single pulse $Z_{L(s)}$ mH $V_{bb}=12V, T_{jstart}=150 \text{ °C};$ (see diagrams on page 12) $I_L = 6 \text{ A}, E_{AS} = 0.319 \text{ J}, R_L = 0 \Omega$, one channel:9.8 $I_L = 12 \text{ A}, E_{AS} = 0.679 \text{ J}, R_L = 0 \Omega$, two parallel channels:5.2Electrostatic discharge voltageIN: V_{ESD} 1.0kV(Human Body Model)IS:2.0according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998 OUT:4.0VVoltage at current limit adjustment pin V_{CLA} -1016VVoltage at current limit adjustment pin I_{CLA} ± 5.0 mH	Maximum voltage across DMOS	V _{ON}	52			
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Load dump protection ³⁾ $V_{\text{LoadDump}} = V_{\text{A}} + V_{\text{S}}$; $V_{\text{A}} = 13,5 \text{ V}$	VLoaddump				
$R_L = 6.8 \Omega$ 53Load current (Short - circuit current, see page 7) I_L $I_{L(lim)}^{5}$ Operating temperature range T_j -40+150Storage temperature range T_{stg} -55+150Dynamical temperature rise at switching dT 60 KPower dissipation ⁶) (DC), one channel active $T_A = 85 ^{\circ}$ C P_{tot} 1.4 WMaximal switchable inductance, single pulse $Z_{L(s)}$ mh $V_{bb}=12V, T_{jstart}=150^{\circ}$ C;(see diagrams on page 12) $I_L = 6 A, E_{AS} = 0.319 J, R_L = 0 \Omega$, one channel: 9.8 $I_L = 12 A, E_{AS} = 0.679 J, R_L = 0 \Omega$, two parallel channels: 5.2 5.2 5.2 Electrostatic discharge voltageIN: V_{ESD} 1.0 kV(Human Body Model)IS: 2.0 $according to ANSI EOS/ESD - S5.1 - 1993$, ESD STM5.1 - 1998OUT: 4.0 Continuous input voltage V_{IN} -1016 V $V_{Oltage at current limit adjustment pin$ I_{CLA} ± 5.0 mA	In = low or high; t_{d} = 400 ms; $R_{l}^{(4)}$ = 2 Ω					
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$R_{\rm L}$ = 2.25 Ω		40			
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$R_{\rm L}$ = 6.8 Ω		53			
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Load current (Short - circuit current, see page 7)	I _L	$I_{L(lim)}^{5)}$	А		
Dynamical temperature rise at switching dT 60 KPower dissipation ⁶⁾ (DC), one channel active $T_A = 85 ^{\circ}\text{C}$ P_{tot} $1,4$ WMaximal switchable inductance, single pulse $Z_{L(s)}$ mh $V_{bb}=12V, T_{jstart}=150^{\circ}\text{C};$ (see diagrams on page 12) $I_L = 6 \text{ A}, E_{AS} = 0.319 \text{ J}, R_L = 0 \Omega$, one channel: 9.8 $I_L = 12 \text{ A}, E_{AS} = 0.679 \text{ J}, R_L = 0 \Omega$, two parallel channels: 5.2 5.2 Electrostatic discharge voltageIN: V_{ESD} 1.0 (Human Body Model)IS: 2.0 according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998 OUT: 4.0 Voltage at current limit adjustment pin V_{CLA} -1016 Vurrent through current limit adjustment pin I_{CLA} ± 5.0	Operating temperature range	T _j		°C		
Dynamical temperature rise at switching dT 60 KPower dissipation ⁶⁾ (DC), one channel active $T_A = 85 ^{\circ}$ C P_{tot} $1,4$ WMaximal switchable inductance, single pulse $Z_{L(s)}$ mh $V_{bb}=12V, T_{jstart}=150^{\circ}$ C;(see diagrams on page 12) $I_L = 6 A, E_{AS} = 0.319 J, R_L = 0 \Omega$, one channel: 9.8 $I_L = 12 A, E_{AS} = 0.679 J, R_L = 0 \Omega$, two parallel channels: 5.2 5.2 Electrostatic discharge voltageIN: V_{ESD} 1.0 (Human Body Model)IS: 2.0 according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998 OUT: 4.0 Voltage at current limit adjustment pin V_{CLA} -1016 Vurrent through current limit adjustment pin I_{CLA} ± 5.0	Storage temperature range	T _{stg}	-55+150			
Maximal switchable inductance, single pulse $Z_{L(s)}$ min $V_{bb}=12V, T_{jstart}=150^{\circ}C;$ (see diagrams on page 12) $I_{L} = 6 A, E_{AS} = 0.319 J, R_{L} = 0 \Omega,$ one channel: 9.8 $I_{L} = 12 A, E_{AS} = 0.679 J, R_{L} = 0 \Omega,$ two parallel channels: 5.2 5.2 Electrostatic discharge voltageIN: V_{ESD} 1.0 (Human Body Model)IS: 2.0 according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998OUT: 4.0 Voltage at current limit adjustment pin V_{CLA} -1016 Current through current limit adjustment pin I_{CLA} ± 5.0	Dynamical temperature rise at switching		60	К		
Maximal switchable inductance, single pulse $Z_{L(s)}$ min $V_{bb}=12V, T_{jstart}=150^{\circ}C;$ (see diagrams on page 12) $I_{L} = 6 A, E_{AS} = 0.319 J, R_{L} = 0 \Omega,$ one channel:9.8 $I_{L} = 12 A, E_{AS} = 0.679 J, R_{L} = 0 \Omega,$ two parallel channels:5.25.2Electrostatic discharge voltageIN: V_{ESD} 1.0kV(Human Body Model)IS:2.02.0according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998OUT:4.0VVoltage at current limit adjustment pin V_{CLA} -1016VVoltage at current limit adjustment pin I_{CLA} ± 5.0 m/A	Power dissipation ⁶⁾ (DC), one channel active $T_A = 85 \degree C$	P _{tot}	1,4	W		
V_{bb} =12V, T_{jstart} =150°C; (see diagrams on page 12)I9.8 I_L = 6 A, E_{AS} = 0.319 J, R_L = 0 Ω , one channel:9.8 I_L = 12 A, E_{AS} = 0.679 J, R_L = 0 Ω , two parallel channels:5.2Electrostatic discharge voltageIN: V_{ESD} (Human Body Model)IS:2.0according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998 OUT:4.0Continuous input voltage V_{IN} -1016Voltage at current limit adjustment pin V_{CLA} -1016Current through current limit adjustment pin I_{CLA} ± 5.0	Maximal switchable inductance, single pulse			mH		
$I_{L} = 12 \text{ A}, E_{AS} = 0.679 \text{ J}, R_{L} = 0 \Omega$, two parallel channels:5.2Electrostatic discharge voltageIN: V_{ESD} 1.0(Human Body Model)IS:2.0according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998 OUT:4.0Continuous input voltage V_{IN} -1016Voltage at current limit adjustment pin V_{CLA} -1016Current through current limit adjustment pin I_{CLA} ± 5.0	V_{bb} =12V, T_{jstart} =150°C; (see diagrams on page 12)					
Electrostatic discharge voltageIN: V_{ESD} 1.0kV(Human Body Model)IS:2.02.02.02.0according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998OUT:4.04.0Continuous input voltage V_{IN} -1016VVoltage at current limit adjustment pin V_{CLA} -1016MACurrent through current limit adjustment pin I_{CLA} ± 5.0 mA	$I_{\rm L} = 6 \text{ A}, E_{\rm AS} = 0.319 \text{ J}, R_{\rm L} = 0 \Omega$, one channel:		9.8			
(Human Body Model)IS:2.0according to ANSI EOS/ESD - S5.1 - 1993, ESD STM5.1 - 1998OUT:4.0Continuous input voltage V_{IN} -1016Voltage at current limit adjustment pin V_{CLA} -1016Current through current limit adjustment pin I_{CLA} ±5.0	$I_{\rm L}$ = 12 A, $E_{\rm AS}$ = 0.679 J, $R_{\rm L}$ = 0 Ω , two parallel channels:		5.2			
according to ANSI EOS/ESD - S5.1 - 1993 , ESD STM5.1 - 1998 OUT:4.0Continuous input voltage V_{IN} -1016Voltage at current limit adjustment pin V_{CLA} -1016Current through current limit adjustment pin I_{CLA} ±5.0	Electrostatic discharge voltage IN:	V _{ESD}	1.0	kV		
Continuous input voltage $V_{\rm IN}$ -1016VVoltage at current limit adjustment pin $V_{\rm CLA}$ -1016Current through current limit adjustment pin $I_{\rm CLA}$ ± 5.0 m/	(Human Body Model) IS:		2.0			
Voltage at current limit adjustment pin V_{CLA} -1016Current through current limit adjustment pin I_{CLA} ±5.0	according to ANSI EOS/ESD - S5.1 - 1993 , ESD STM5.1 - 1998 OUT:		4.0			
Current through current limit adjustment pin I_{CLA} ± 5.0 m/	Continuous input voltage	V _{IN}	-1016	V		
Current through current limit adjustment pin I _{CLA} ±5.0 mA	Voltage at current limit adjustment pin	V _{CLA}	-1016			
	Current through current limit adjustment pin		±5.0	mA		
	Current through input pin (DC)	I _{IN}	±5.0			
Current through sense (DC) (see page 11) I_{IS} -5+10	Current through sense (DC) (see page 11)	I _{IS}	-5+10			

¹18...28 V for 100 hours

²only single pulse, $R_L = 200 \text{ m}\Omega$; $L = 8 \mu\text{H}$; R and L are describing the complete circuit impedance including line, contact and generator impedances.

³Supply voltage higher than $V_{bb(AZ)}$ require an external current limit for the GND(150 Ω resistor) and sense pin.

 ${}^{4}R_{I}$ = internal resistance of the load dump test pulse generator.

⁵Current limit is a protection function. Operation in current limitation is considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

⁶Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm2 (one layer, 70 μ m thick) copper area for V_{bb} connection. PCB is vertical without blown air.



Electrical Characteristic	S	Í					1
Parameter and Condition	ns, each of the two char	nnels	Symbol		Values		Unit
at T_{j} = -40+150 °C, V_{bb} = 9	16 V, unless otherwise s	pecified		min.	typ.	max.	
Thermal Resistance							
junction - case	each	channe	R _{thJC}	-	-	1.8	K/W
junction - ambient ¹⁾	one channel	active:	<i>R</i> thJA	-	40	-	K/W
	all channels	active:		-	33	-	
Load Switching Capabi	ities and Characte	eristics				•	
On-state resistance (V _{bb}	to OUT), (see pag	ie 13)	R _{ON}				mΩ
<i>T</i> _j = 25 °C, <i>I</i> _L = 5 A,	each ch	annel:		-	21	25	
<i>T</i> _j = 150 °C,	each ch	annel:		-	42	50	
<i>T</i> _j = 25 °C,	two parallel cha	innels:		-	11	13	
Nominal load current ¹⁾			I _{L(nom)}				A
$T_{a} = 85^{\circ}C, \ T_{j} \le 150^{\circ}C$,	one channel a	active:		5.5	6	-	
two chai	nnels active, per ch	annel:		4.1	4.5	-	
Nominal load current; IS	O Norm		I _{L(ISO)}				
$T_{\rm C}$ = 85 °C, $V_{\rm ON}$ = 0.5 V,	one channel a	active:		13	15	-	
two cha	nnels active, per ch	annel:		13	15	-	
Output voltage drop limita	ition at small load c	urrents	V _{ON(NL)}	-	40	-	mV
<i>I</i> _L = 0.5 A							
Output current while GNE	disconnected ²⁾		I _{L(GNDhigh)}	-	-	2	mA
(see diagram page 12)							
$V_{\rm IN} = 0 V$							

 $^{1}\text{Device}$ on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm2 (one layer, 70µm thick) copper area for V_{bb} connection. PCB is vertical without blown air.

²not subject to production test, specified by design



Parameter and Conditions, each of the two channels	Symbol	Values			Unit
at T_j = -40+150 °C, V_{bb} = 916 V, unless otherwise specified		min.	typ.	max.	
Load Switching Capabilities and Characteristics			-		
Turn-on time ¹⁾ to 90% V _{OUT}	t _{on}	-	90	200	μs
$R_{\rm L}$ = 12 Ω, $V_{\rm bb}$ = 12 V					
Turn-off time ¹⁾ to 10% V _{OUT}	t _{off}	-	100	220	
$R_{\rm L}$ = 12 Ω, $V_{\rm bb}$ = 12 V					
Slew rate on ¹⁾ 10 to 30% V _{OUT} ,	dV/dt _{on}	0.1	0.25	0.45	V/µs
$R_{\rm L}$ = 12 Ω, $V_{\rm bb}$ = 12 V					
Slew rate off ¹⁾ 70 to 40% V _{OUT} ,	-dV/dt _{off}	0.09	0.25	0.4	
$R_{\rm L}$ = 12 Ω, $V_{\rm bb}$ = 12 V					

Operating Parameters

Operating voltage ²⁾	V _{bb(on)}	4.5	-	28	V
Overvoltage protection ³⁾	V _{bb(AZ)}	41	47	52	
<i>I</i> _{bb} = 40 mA					
Standby current ⁴⁾	I _{bb(off)}				μA
(see diagram on page 13)					
<i>T</i> _j = −40+25 °C, <i>V</i> _{IN} = 0 V		-	5	7.5	
<i>T</i> _j = 150 °C		-	-	20	

¹See timing diagram on page 14.

218V...28V for 100 hours

³Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the status pin and GND pin (e.g. 150 Ω). See also $V_{Out(CL)}$ in table of protection functions and circuit diagram on page 11.

⁴Measured with load; for the whole device; all channels off.



Electrical Characteristics		1	1			1
Parameter and Conditions	, each of the two channels	Symbol		Values) 	Unit
at T_{j} = -40+150 °C, V_{bb} = 916	V, unless otherwise specified		min.	typ.	max.	
Operating Parameters						
Off-State output current (inc	luded in <i>I_{bb(off)})</i>	I _{L(off)}	-	1.5	8	μA
$V_{\rm IN}$ = 0 V, each channel						
Operating current ¹⁾		I _{GND}	-	1.6	4	mA
$V_{\rm IN}$ = 5 V, per active channel	el					
Protection Functions ²⁾						
Current limit, (see timing diag	rams, page 15)	I _{L(LIM)}				A
Low level; if potent	ial at CLA = high		7	11	14	
High level; if poten	tial at CLA = low		40	50	60	
Current limit adjustment three	eshold voltage	V _{CLA(T-)}	2.0	-	-	V
		V _{CLA(T+)}	-	-	4.0	
Repetitive short circuit curre	ent limit	I _{L(SCr)}				Α
$T_j = T_{jt}$ (see timing diagrams o	n page 15)					
High level	one active channel:		-	40	-	
	two active channels ³⁾ :		-	40	-	
Low level	one active channel:		-	7	-	
	two active channels ³⁾		-	7	-	
Initial short circuit shutdown	time low level:	t _{off(SC)}	-	4	-	ms
<i>T</i> _{j,start} = 25°C ; <i>V</i> _{bb} = 13,5 \	/ high level:		-	0.8	-	
Output clamp (inductive loa	d switch off) ⁴⁾	V _{Out(CL)}	-	-15	-	V
<i>I</i> _L = 40 mA						
Thermal overload trip tempe	erature	T _{it}	150	170	-	°C
Thermal hysteresis		ΔT_{it}	-	10	-	К

¹Add I_{IS} , if $I_{IS} > 0$

²Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

³At the beginning of the short circuit the double current is possible for a short time.

⁴If channels are connected in parallel, output clamp is usually accomplished by the channel with the lowest $V_{Out(CL)}$.



Electrical Characteristics					
Parameter and Conditions, each of the two channels	Symbol		Values		Unit
at T_{j} = -40+150 °C, V_{bb} = 916 V, unless otherwise specified		min.	typ.	max.	
Diagnostic Characteristics					
Open load detection voltage	V _{OUT(OL)}	2	3.2	4.4	V
Internal output pull down ¹⁾	R _{OUT(PD)}	11	23	35	kΩ
V _{OUT} = 13.5 V					
Current sense ratio, static on-condition	k _{ILIS}				
$k_{\rm ILIS} = I_{\rm L} : I_{\rm IS}$					
<i>I</i> _L = 0.5 A		4640	5800	6960	
<i>I</i> _L = 3 A		4900	5400	5900	
$I_{\rm L} = 6 {\rm A}$		4900	5350	5800	
Sense signal in case of fault-conditions ²⁾	V _{fault}	5	6.2	7.5	V
in off-state					
Current saturation of sense fault signal	l _{fault}	4	-	-	mA
Sense signal delay after thermal shutdown ³⁾	t _{delay(fault)}	-	-	1.2	ms
Current sense output voltage limitation	V _{IS(lim)}	5.4	6.5	7.3	V
l _{IS} = 0 , l _L = 5 Α					
Current sense leakage/offset current	I _{IS(LH)}	-	-	5	μA
$V_{\rm IN} = 5 \text{V}, I_{\rm L} = 0 , V_{\rm IS} = 0$					
Current sense settling time to I_{IS} static ±10%	t _{son(IS)}	-	-	400	μs
after positive input slope ⁴⁾ , $I_{\rm L}$ = 0 to 5A					
Current sense settling time to I_{IS} static ±10%	t _{slc(IS)}	-	-	300	
after change of load current ⁴⁾ , $I_{\rm L}$ = 2.5 to 5A					

¹In case of floating output, the status doesn't show open load.

²Fault condition means output voltage exceeds open load detection voltage V_{OUT(OL)}

³In the case of thermal shutdown the V_{fault} signal remains for $t_{\text{delay}(\text{fault})}$ longer

than the restart of the switch (see diagram on page 16). Not subject to production test, specified by design.

⁴not subject to production test, specified by design



Electrical Characteristics

Parameter	Symbol	Values		Unit	
_at T_j = -40+150 °C, V_{bb} = 916 V, unless otherwise specified		min.	typ.	max.	
Diagnostic Characteristics					
Status invalid after negative input slope	t _{d(SToff)}	-	-	1.2	ms
Status invalid after positive input slope	t _{d(STOL)}	-	-	20	μs
with open load					
Input Feedback ¹⁾					
Input resistance (see circuit page 11)	R _I	2.0	3.5	5.5	kΩ
Input turn-on threshold voltage	V _{IN(T+)}	-	-	2.4	V
Input turn-off threshold voltage	V _{IN(T-)}	1.0	-	-	
Input threshold hysteresis	$\Delta V_{\rm IN(T)}$	-	0.5	-	
Off state input current	I _{IN(off)}	3	-	40	μA
$V_{\rm IN} = 0.4 \ V$					
On state input current	I _{IN(on)}	20	50	90]
$V_{\rm IN} = 5 V$					

Reverse Battery²⁾

Reverse battery voltage	-V _{bb}	-	-	27	V
Drain-source diode voltage ($V_{OUT} > V_{bb}$)	-V _{ON}	-	330	-	mV
<i>T</i> _j = 150 °C, <i>I</i> _{bb} = -10 mA					

¹If ground resistors R_{GND} are used, add the voltage drop across these resistor.

 2 Requires a 150 Ω resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input and status currents have to be limited. (see max. ratings page 4)



	Input	Output	Diagnostic
	level	level	output
Normal	L	L	Z ¹⁾
Operation	Н	$V_{ m bb}$	I _{IS} = I _L / kilis
Current Limitation ²⁾	Н	V _{bb}	V _{fault}
Short circuit	L	L	Z ¹⁾
to GND	Н	L	V _{fault}
Overtemperature	L	L	Z ¹⁾
	Н	L	V _{fault}
Short circuit	L	V _{bb}	V _{fault}
to V _{bb}	Н	$V_{\rm bb}$	$< I_{\rm IS} = I_{\rm L} / \rm kilis^{3}$
Open load	L	>V _{out(OL)}	V _{fault}
	Н	V _{bb}	Z ¹⁾

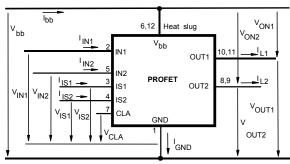
Truth Table - for each of the two channels

L = "Low" Level Z = high impedance, potential depends on external circuit

H = "High" Level V_{fault} = 5V typ., constant voltage independent of external sense resistor.

Parallel switching of channels is possible by connecting the inputs and outputs parallel. The current sense ouputs have to be connected with a single sense resistor.

Terms



Leadframe / heat slug ($V_{\rm bb}$) is connected to pin 6,12.

¹L-potential by using a sense resistor

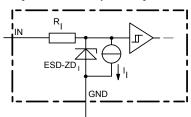
²Current limitation is only possible while the device is switched on.

³Low ohmic short to V_{bb} may reduce the output current I_L and therefore also the sense current I_{IS} .



BTS 5240L

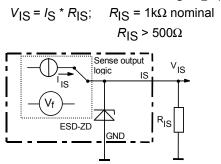
Input circuit (ESD protection), IN1 or IN2



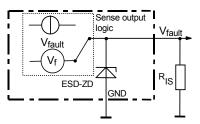
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

Sense-Status output, IS1 or IS2

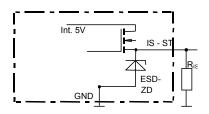
ON-State: Normal operation: $I_{S} = I_{L} / KILIS$



ESD zener diode: V_{ESD} = 6,1 V typ., max. 14 mA ; ON-State: Fault condition so as thermal shut down or current limitation

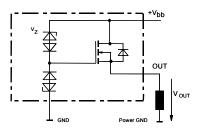


 $V_{\text{fault}} = 6 \text{ V typ}$; $V_{\text{fault}} < V_{\text{ESD}}$ under all conditions OFF-State diagnostic condition: Open Load, if $V_{\text{OUT}} > 3 \text{ V typ.}$; IN low



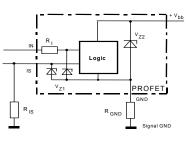
ESD-Zener diode: 6,1V typ., max. 5mA; $R_{ST(ON)} < 375\Omega$ at 1,6mA.. The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

Inductive and overvoltage output clamp, OUT1 or OUT2



 V_{Out} clamped to $V_{Out(CL)}$ = -15 V typ.

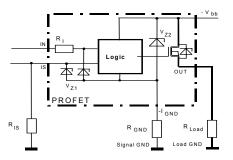
Overvolt. Protection of logic part OUT1 or OUT2



$$\begin{split} V_{Z1} &= 6,1 \text{V typ.}, \, V_{Z2} = 47 \text{V typ.}, \, R_{\text{GND}} = 150 \Omega \;, \\ R_{\text{IS}} &= 1 \text{k} \Omega \;, \, R_{\text{I}} = 3,5 \text{k} \Omega \; \text{typ.} \end{split}$$



Reverse battery protection OUT1 or OUT2

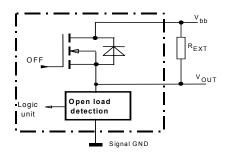


 $V_{Z1} = 6,1V$ typ., $V_{Z2} = 47V$ typ., $R_{GND} = 150\Omega$ $R_{IS} = 1k\Omega$, $R_{I} = 3,5k\Omega$ typ.

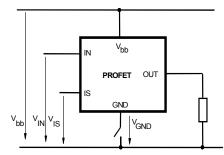
In case of reverse battery the load current has to be limited by the load. Protection functions are not active.

Open load detection, OUT1 or 2

Off-state diagnostic condition: Open load, if V_{OUT} > 3 V typ.; IN = low

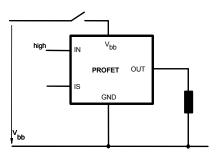


GND disconnect



Any kind of load.

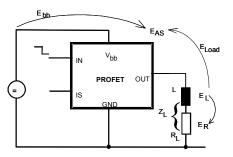
Vbb disconnect with energized inductive load



For inductive load currents up to the limits defined by Z_L each switch is protected against loss of V_{bb} .

(max. ratings and diagram on page 12) Consider at your PCB layout that in the case of Vbb disconnection with energized inductive load all the load current flows through the GND connection.

Inductive load switch-off energy dissipation

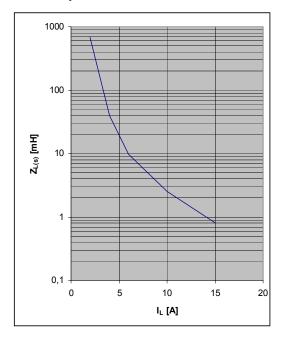


Energy stored in load inductance: $E_L = \frac{1}{2} * L * I_L^2$ While demagnetizing load inductance, the energy dissipated in PROFET is $E_{AS} = E_{bb} + E_L - E_R = V_{ON(CL)} * i_L(t) dt$, with an approximate solution for $R_L > 0\Omega$:

$$E_{AS} = \frac{I_L * L}{2 * R_L} * (V_{bb} + |V_{OUT(CL)|}) * \ln(1 + \frac{I_L * R_L}{|V_{OUT(CL)|}})$$

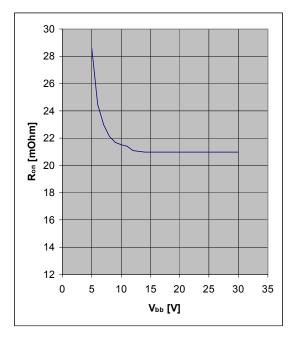


Maximum allowable load inductance for a single switch off (one channel) L =f(IL); T_{jstart} = 150°C, V_{bb} = 12V, R_L = 0 Ω



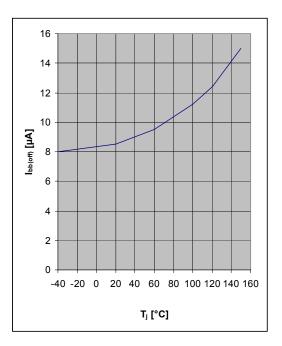
Typ. on-state resistance

 $R_{ON} = f(V_{bb}, T_j); I_L = 5 \text{ A}; V_{in} = \text{high}$



Typ. standby current

 $I_{bb(off)} = f(T_j)$; $V_{bb} = 16 V$; $V_{IN1,2} = Iow$

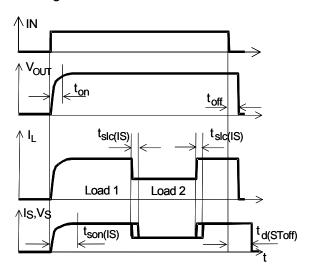




Timing diagrams

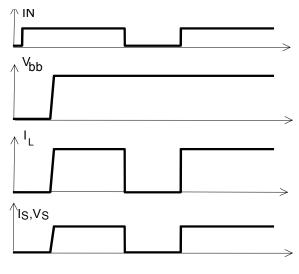
All channels are symmetric and consequently the diagrams are valid for channel 1 and channel 2.

Figure 1a: Switching a resistive load, change of load current in on-condition



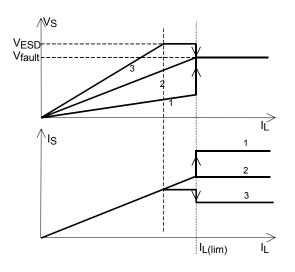
The sense signal is not valid during settling time after turn on or change of load current. $tslc(IS) = 300 \ \mu s \ max$.

Figure 1b: V_{bb} turn on



proper turn on under all conditions

Figure 1c: Behaviour of sense output: Sense current (I_S) and sense voltage (V_S) as function of load current dependent on the sense resistor. Shown is V_S and I_S for three different sense resistors. Curve 1 refers to a low resistor, curve 2 to a medium-sized resistor and curve 3 to a big resistor. Note, that the sense resistor may not falls short of a minimum value of 500 Ω .



 $I_{\rm S} = I_{\rm L} / k_{\rm ILIS}$ $V_{\rm IS} = I_{\rm S} * R_{\rm IS}; R_{\rm IS} = 1 {\rm k} \Omega \text{ nominal}$ $R_{\rm IS} > 500 \Omega$

BTS 5240L



Figure 2a: Switching a lamp

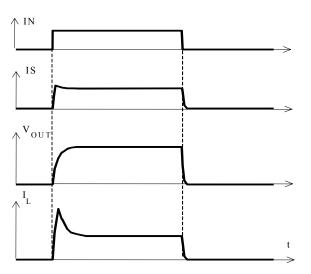


Figure 2b: Switching a lamp with current limit: The behaviour of I_S and V_S is shown for a resistor, which refers to curve 1 in figure 1c

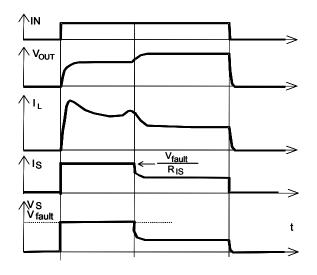
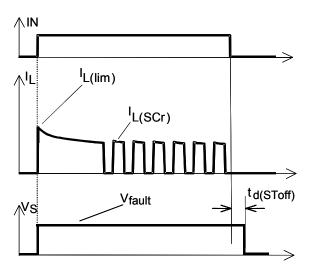


Figure 3a: Short circuit: Shut down by overtemperature, reset by cooling



Heating up may require several milliseconds, depending on external conditions. $I_{L(lim)} = 50A$ typ. increases with decreasing temperature.

Figure 3b: Turn on into short circuit, shut down by overtemperature, restart by cooling (channel 1 and 2 switched parallel)

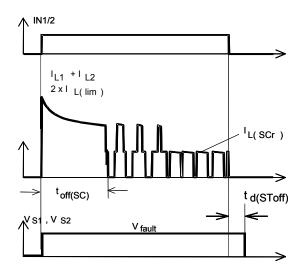
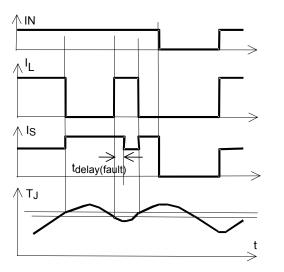




Figure 4a: Overtemperature Reset if $T_j < T_{jt}$

The behaviour of I_S and V_S is shown for a resistor, which refers to curve 1 in figure 1c.



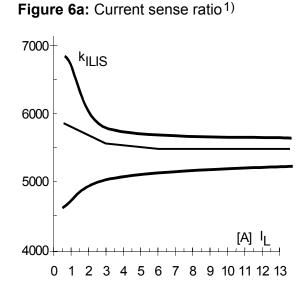
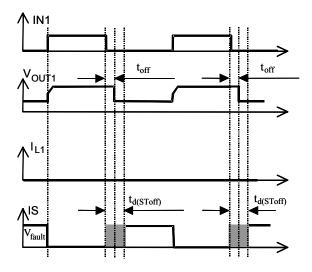


Figure 5a:Open-load: detection in OFF-state, turn on/off to open load.

Open load of channel 1; other channels normal opertaion.



 t_{Off} = 220µs max.; $t_{d(\text{SToff})}$ = 1,2ms max. with pull up resistor at output

¹This range for the current sense ratio refers to all devices. The accuracy of the $k_{|L|S}$ can be raised by calibrating the value of $k_{|L|S}$ for every single device.

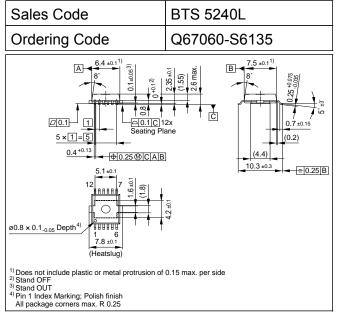


BTS 5240L

Package and ordering code

all dimensions in mm

P-DSO-12-2



Published by Infineon Technologies AG, St.-Martin-Strasse 53, D-81669 München © Infineon Technologies AG 2001 All Rights Reserved.

Attention please!

The information herein is given to describe certain components and shall not be considered as a guarantee of characteristics.

Terms of delivery and rights to technical change reserved.

We hereby disclaim any and all warranties, including but not limited to warranties of non-infringement, regarding circuits, descriptions and charts stated herein.

Infineon Technologies is an approved CECC manufacturer.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide (see address list).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.